



# Small Signal Fast Switching Diode



### FEATURES

- Silicon epitaxial planar diode
- Fast switching diode
- AEC-Q101 qualified
- Base P/N-E3 - RoHS-compliant, commercial grade
- Base P/N-HE3 - RoHS-compliant, AEC-Q101 qualified
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



RoHS COMPLIANT

### MECHANICAL DATA

Case: SOD-123

Weight: approx. 10.3 mg

Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box

08/3K per 7" reel (8 mm tape), 15K/box

| PARTS TABLE |                                  |                       |              |               |
|-------------|----------------------------------|-----------------------|--------------|---------------|
| PART        | ORDERING CODE                    | INTERNAL CONSTRUCTION | TYPE MARKING | REMARKS       |
| 1N4448W     | 1N4448W-E3-08 or 1N4448W-E3-18   | Single diode          | A3           | Tape and reel |
|             | 1N4448W-HE3-08 or 1N4448W-HE3-18 |                       |              |               |

| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)      |                                    |                    |       |      |
|--|------------------------------------|--------------------|-------|------|
| PARAMETER  | TEST CONDITION                     | SYMBOL             | VALUE | UNIT |
| Reverse voltage  |                                    | V <sub>R</sub>     | 75    | V    |
| Repetitive peak reverse voltage  |                                    | V <sub>RRM</sub>   | 100   | V    |
| Average rectified current half wave rectification with resistive load <sup>(1)</sup> | f ≥ 50 Hz                          | I <sub>F(AV)</sub> | 150   | mA   |
| Surge current  | t < 1 s and T <sub>j</sub> = 25 °C | I <sub>FSM</sub>   | 500   | mA   |
| Power dissipation <sup>(1)</sup>   |                                    | P <sub>tot</sub>   | 500   | mW   |

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                   |               |      |
|--|----------------|-------------------|---------------|------|
| PARAMETER  | TEST CONDITION | SYMBOL            | VALUE         | UNIT |
| Thermal resistance junction to ambient air <sup>(1)</sup>                      |                | R <sub>thJA</sub> | 350           | K/W  |
| Junction temperature   |                | T <sub>j</sub>    | 150           | °C   |
| Storage temperature  |                | T <sub>stg</sub>  | - 65 to + 150 | °C   |
| Operating temperature  |                | T <sub>op</sub>   | - 55 to + 150 | °C   |

### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature.

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |  |          |      |      |      |               |
|--|--|----------|------|------|------|---------------|
| PARAMETER  | TEST CONDITION   | SYMBOL   | MIN. | TYP. | MAX. | UNIT          |
| Forward voltage  | $I_F = 5\text{ mA}$  | $V_F$    | 0.62 |      | 0.72 | V             |
|  | $I_F = 100\text{ mA}$  | $V_F$    |      |      | 1    | V             |
| Leakage current  | $V_R = 20\text{ V}$  | $I_R$    |      |      | 25   | nA            |
|  | $V_R = 75\text{ V}$  | $I_R$    |      |      | 5    | $\mu\text{A}$ |
|  | $V_R = 20\text{ V}, T_J = 150\text{ }^{\circ}\text{C}$                             | $I_R$    |      |      | 50   | $\mu\text{A}$ |
| Capacitance  | $V_F = V_R = 0\text{ V}$   |          |      |      | 4    | pF            |
| Reverse recovery time  | $I_F = 10\text{ mA}, i_R = 1\text{ mA}, V_R = 6\text{ V}, R_L = 100\text{ }\Omega$ | $t_{rr}$ |      |      | 4    | ns            |

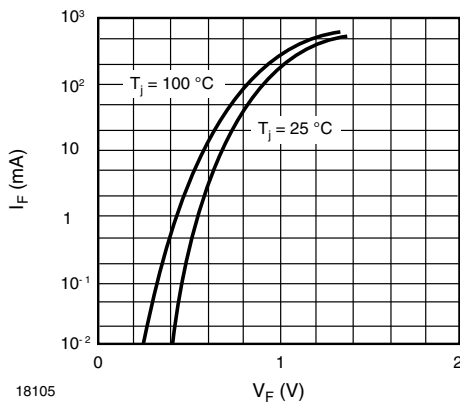
**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)


Fig. 1 - Forward Characteristics

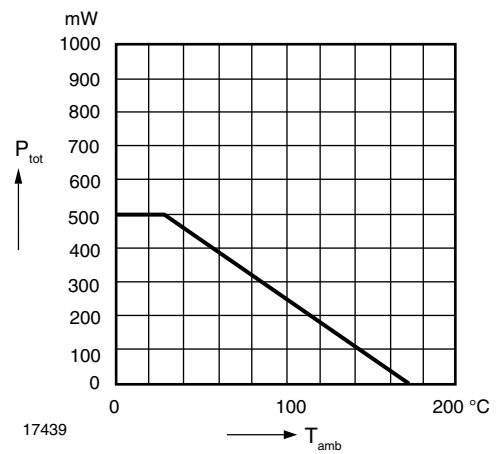


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

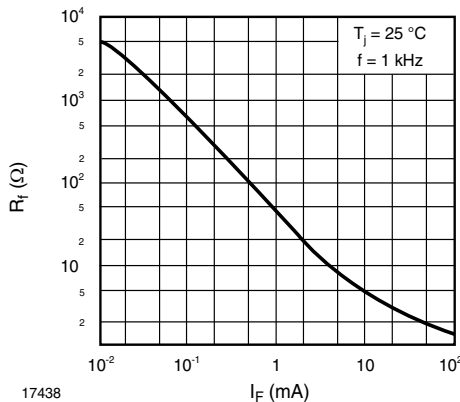


Fig. 2 - Dynamic Forward Resistance vs. Forward Current



Fig. 4 - Relative Capacitance vs. Reverse Voltage



Fig. 5 - Leakage Current vs. Junction Temperature

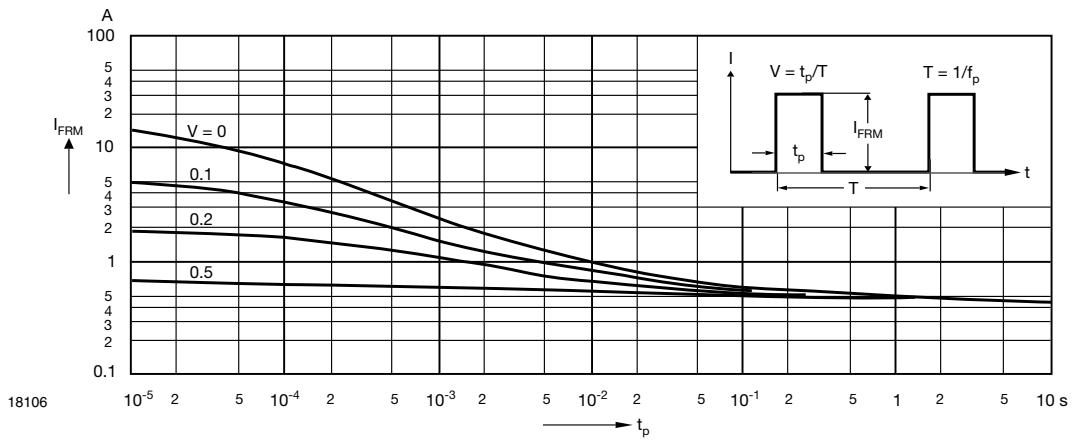
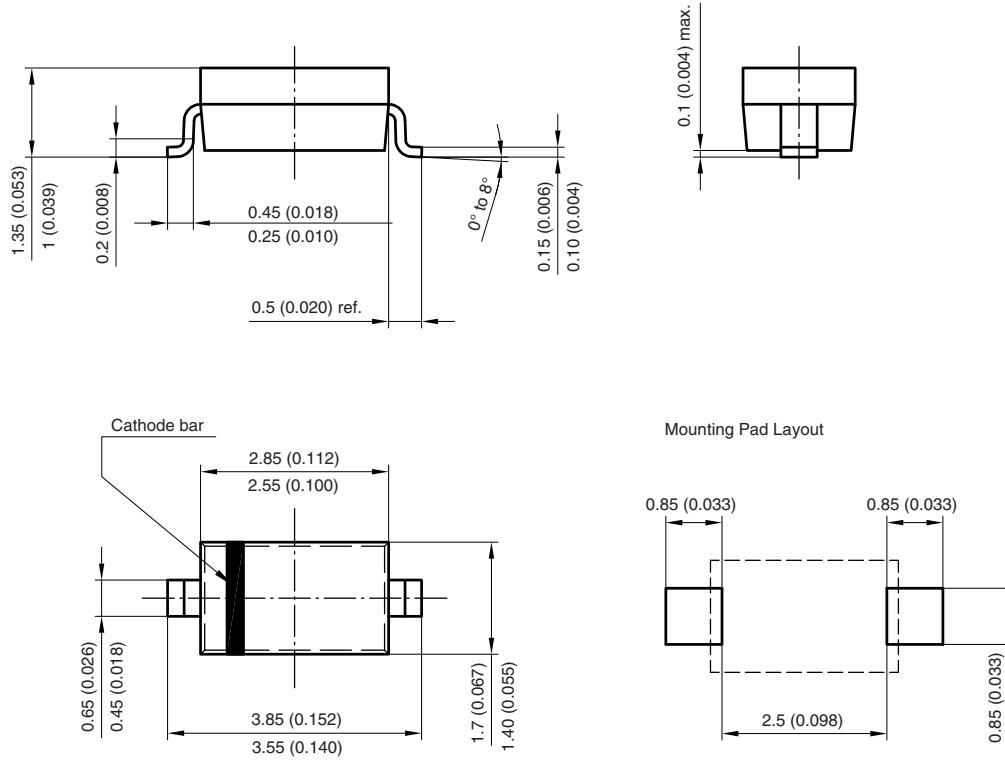


Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration



**PACKAGE DIMENSIONS** in millimeters (inches): **SOD-123**



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